

Features

- Built using the advantages and compatibility of CMOS and IXYS HDMOS™ processes.
- Latch Up Protected
- High Peak Output Current: 8A Peak
- Operates from 4.5V to 25V
- Ability to Disable Output under Faults
- High Capacitive Load
Drive Capability: 2500pF in <15ns
- Matched Rise And Fall Times
- Low Propagation Delay Time
- Low Output Impedance
- Low Supply Current

Applications

- Driving MOSFETs and IGBTs
- Limiting di/dt under Short Circuit
- Motor Controls
- Line Drivers
- Pulse Generators
- Local Power ON/OFF Switch
- Switch Mode Power Supplies (SMPS)
- DC to DC Converters
- Pulse Transformer Driver
- Class D Switching Amplifiers

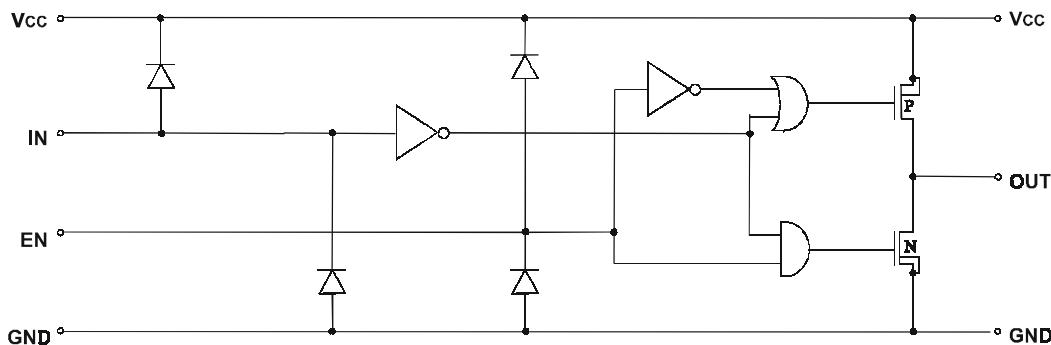
General Description

The IXDD408 is a high speed high current gate driver specifically designed to drive the largest MOSFETs and IGBTs to their minimum switching time and maximum practical frequency limits. The IXDD408 can source and sink 8A of peak current while producing voltage rise and fall times of less than 30ns. The input of the driver is compatible with TTL or CMOS and is fully immune to latch up over the entire operating range. Designed with small internal delays, cross conduction/current shoot-through is virtually eliminated in the IXDD408. Its features and wide safety margin in operating voltage and power make the IXDD408 unmatched in performance and value.

The IXDD408 incorporates a unique ability to disable the output under fault conditions. When a logical low is forced into the Enable input, both final output stage MOSFETs (NMOS and PMOS) are turned off. As a result, the output of the IXDD408 enters a tristate mode and achieves a Soft Turn-Off of the MOSFET/IGBT when a short circuit is detected. This helps prevent damage that could occur to the MOSFET/IGBT if it were to be switched off abruptly due to a dv/dt over-voltage transient.

The IXDD408 is available in the standard 8-pin P-DIP (PI), SOP-8 (SI), 5-pin TO-220 (CI) and in the TO-263 (YI) surface-mount package.

Figure 1 - Functional Diagram



Absolute Maximum Ratings (Note 1)

Parameter	Value
Supply Voltage	25 V
All Other Pins	-0.3 V to $V_{CC} + 0.3$ V
Power Dissipation, $T_{AMBIENT} \leq 25$ °C	
8 Pin PDIP (PI)	975mW
8 Pin SOIC (SI)	1055mW
TO220 (CI), TO263 (YI)	17W
Derating Factors (to Ambient)	
8 Pin PDIP (PI)	7.6mW/°C
8 Pin SOIC (SI)	8.2mW/°C
TO220 (CI), TO263 (YI)	0.14W/°C
Storage Temperature	-65 °C to 150 °C
Lead Temperature (10 sec)	300 °C

Operating Ratings

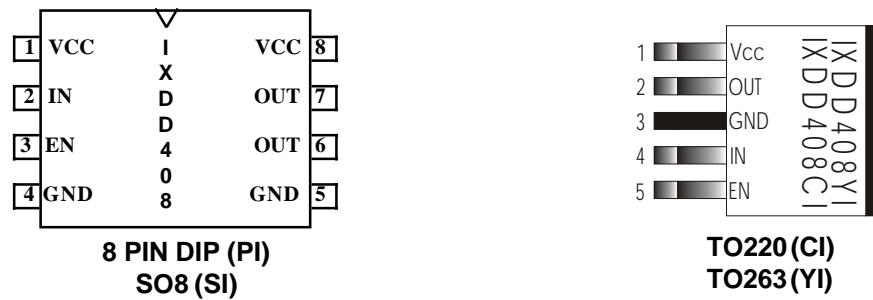
Parameter	Value
Maximum Junction Temperature	150 °C
Operating Temperature Range	-40 °C to 85 °C
Thermal Impedance (Junction To Case)	
TO220 (CI), TO263 (YI) (θ_{JC})	0.95 °C/W

Electrical CharacteristicsUnless otherwise noted, $T_A = 25$ °C, $4.5V \leq V_{CC} \leq 25V$.All voltage measurements with respect to GND. IXDD408 configured as described in *Test Conditions*.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
V_{IH}	High input voltage		3.5			V
V_{IL}	Low input voltage			0.8		V
V_{IN}	Input voltage range		-5		$V_{CC} + 0.3$	V
I_{IN}	Input current	$0V \leq V_{IN} \leq V_{CC}$		-10	10	µA
V_{OH}	High output voltage		$V_{CC} - 0.025$			V
V_{OL}	Low output voltage			0.025		V
R_{OH}	Output resistance @ Output high	$I_{OUT} = 10mA, V_{CC} = 18V$	0.8	1.5		Ω
R_{OL}	Output resistance @ Output Low	$I_{OUT} = 10mA, V_{CC} = 18V$	0.8	1.5		Ω
I_{PEAK}	Peak output current	V_{CC} is 18V		8		A
I_{DC}	Continuous output current	Limited by package power dissipation			2	A
V_{EN}	Enable voltage range				$V_{CC} + 0.3$	V
V_{ENH}	High En Input Voltage		2/3 V_{CC}			V
V_{ENL}	Low En Input Voltage				1/3 V_{CC}	V
t_R	Rise time	$C_L = 2500pF$ $V_{CC} = 18V$	12	14	18	ns
t_F	Fall time	$C_L = 2500pF$ $V_{CC} = 18V$	13	15	19	ns
t_{ONDLY}	On-time propagation delay	$C_L = 2500pF$ $V_{CC} = 18V$	37	38	42	ns
t_{OFFDLY}	Off-time propagation delay	$C_L = 2500pF$ $V_{CC} = 18V$	32	34	38	ns
t_{ENOH}	Enable to output high delay time	$V_{CC} = 18V$			52	ns
t_{DOLD}	Disable to output low Disable delay time	$V_{CC} = 18V$			30	ns
V_{CC}	Power supply voltage		4.5	18	25	V
I_{CC}	Power supply current	$V_{IN} = 3.5V$ $V_{IN} = 0V$ $V_{IN} = + V_{CC}$	1	3		mA
			0	10		µA
					10	µA

Specifications Subject To Change Without Notice

Pin Configurations



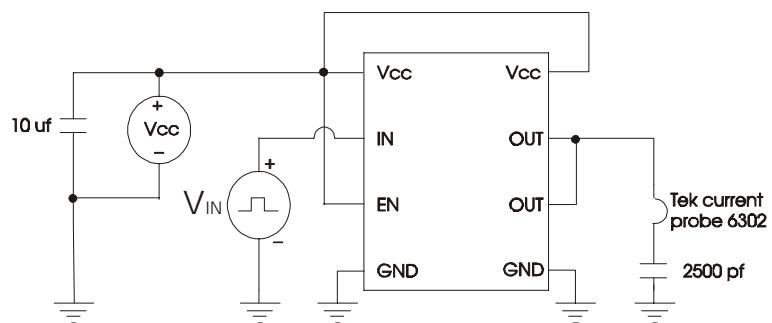
Pin Description

SYMBOL	FUNCTION	DESCRIPTION
VCC	Supply Voltage	Positive power-supply voltage input. This pin provides power to the entire chip. The range for this voltage is from 4.5V to 25V.
IN	Input	Input signal-TTL or CMOS compatible.
EN	Enable	The system enable pin. This pin, when driven low, disables the chip, forcing high impedance state to the output.
OUT	Output	Driver Output. For application purposes, this pin is connected, through a resistor, to Gate of a MOSFET/IGBT.
GND	Ground	The system ground pin. Internally connected to all circuitry, this pin provides ground reference for the entire chip. This pin should be connected to a low noise analog ground plane for optimum performance.

Note 1: Operating the device beyond parameters with listed “absolute maximum ratings” may cause permanent damage to the device. Typical values indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. The guaranteed specifications apply only for the test conditions listed. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

CAUTION: These devices are sensitive to electrostatic discharge; follow proper ESD procedures when handling and assembling this component.

Figure 2 - Characteristics Test Diagram



Typical Performance Characteristics

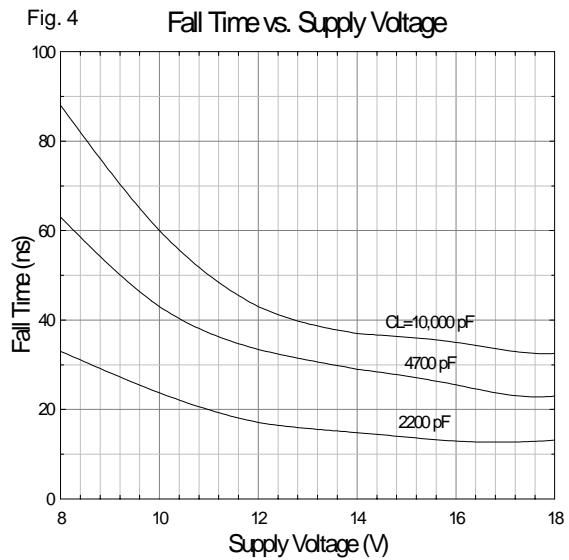
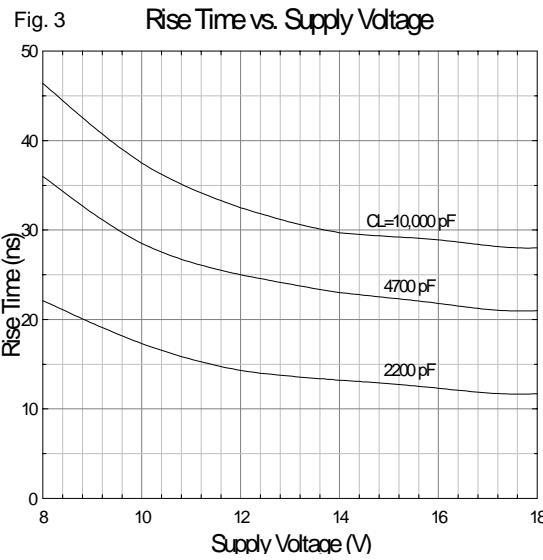


Fig. 5 Rise And Fall Times vs. Junction Temperature
 $C_L = 2500\text{pF}$, $V_{CC} = 18\text{V}$

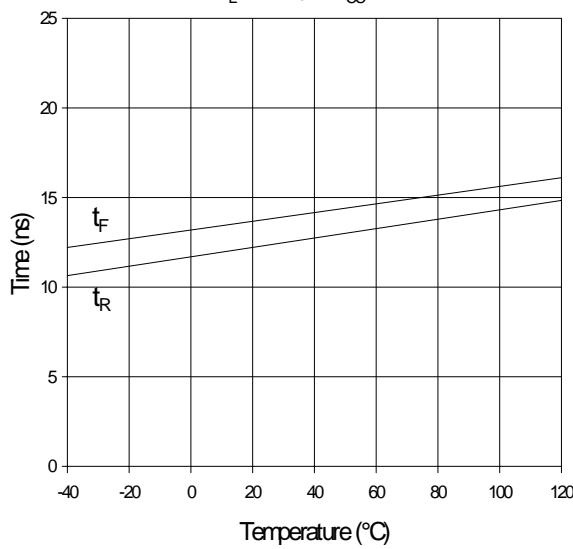


Fig. 7 Fall Time vs. Load Capacitance

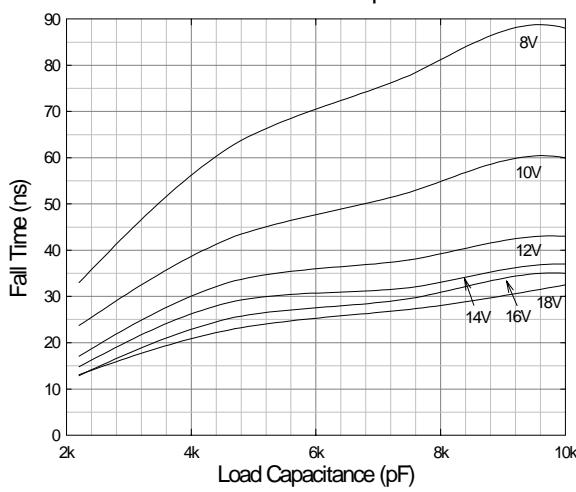


Fig. 6 Rise Time vs. Load Capacitance

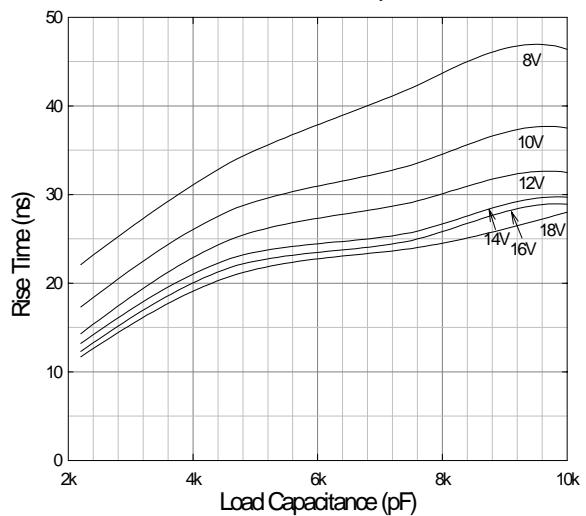


Fig. 8 Max / Min Input vs. Junction Temperature
 $C_L = 2500\text{pF}$, $V_{CC} = 18\text{V}$

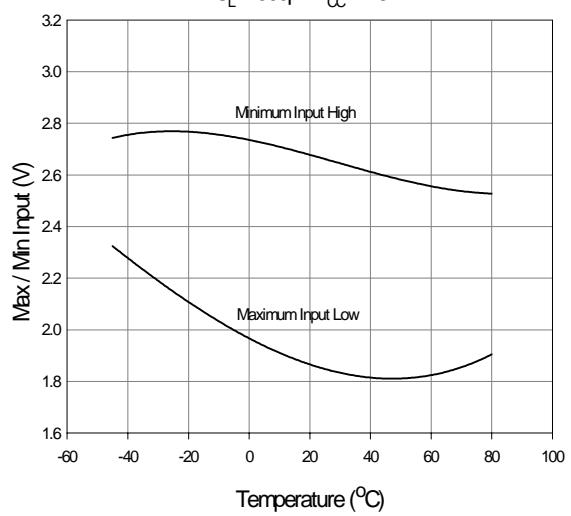


Fig. 9 Supply Current vs. Load Capacitance
V_{cc}=18V

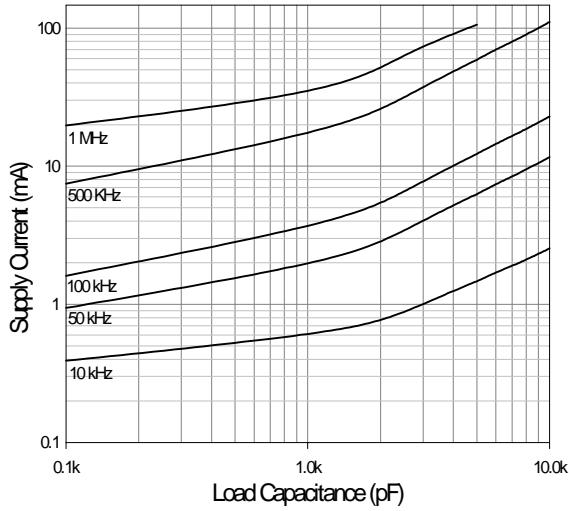


Fig. 11 Supply Current vs. Load Capacitance
V_{cc}=12V

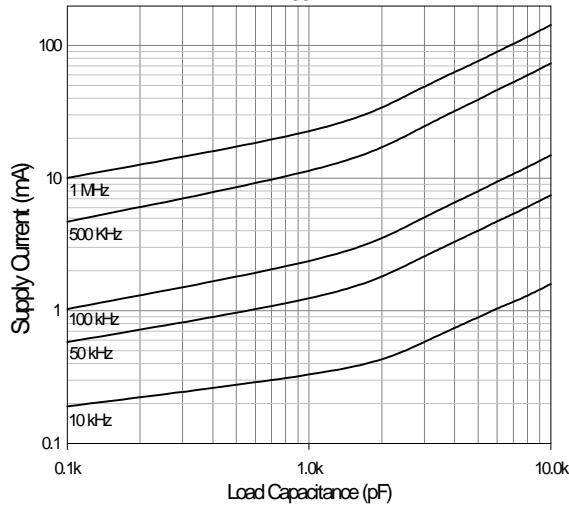


Fig. 13 Supply Current vs. Load Capacitance
V_{cc}=8V

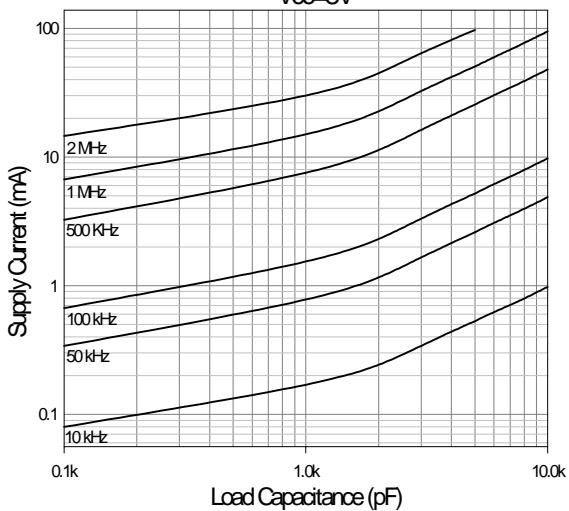


Fig. 10 Supply Current vs. Frequency
V_{cc}=18V

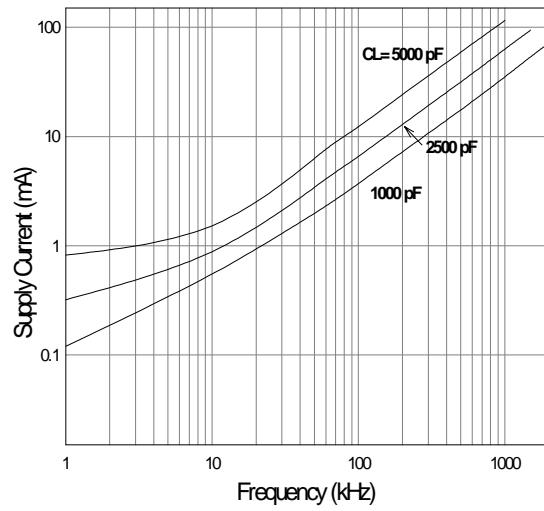


Fig. 12 Supply Current vs. Frequency
V_{cc}=12V

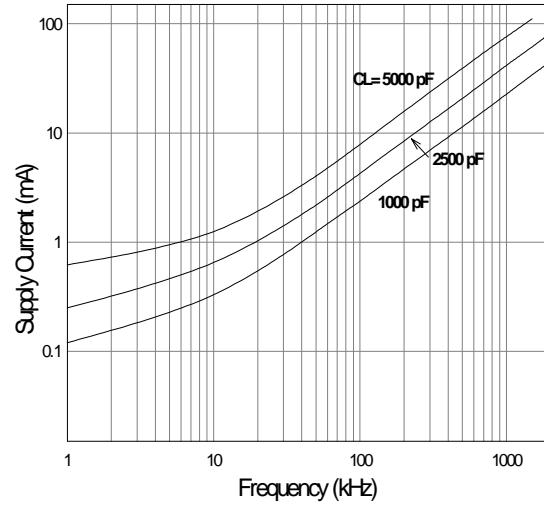


Fig. 14 Supply Current vs. Frequency
V_{cc}=8V

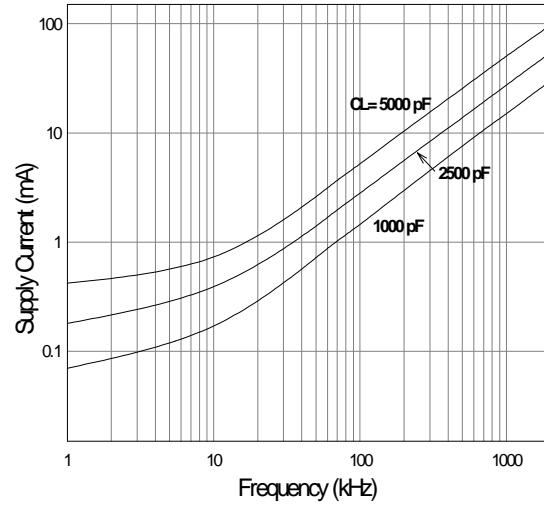


Fig. 15 Propagation Delay vs. Supply Voltage
 $C_L=2500\text{pF}$ $V_{IN}=5\text{V@1kHz}$

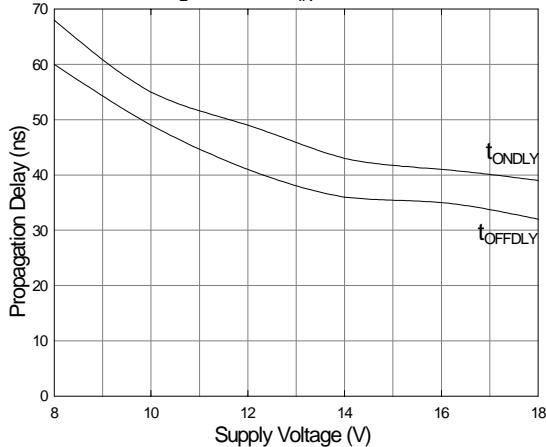


Fig. 16 Propagation Delay vs. Input Voltage
 $C_L=2500\text{pF}$ $V_{CC}=15\text{V}$

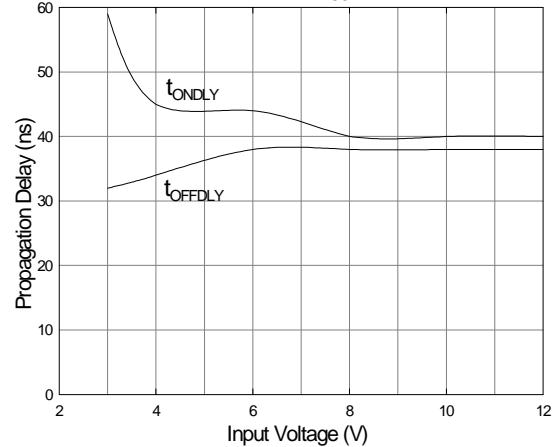


Fig. 17 Propagation Delay Times vs. Junction Temperature
 $C_L=2500\text{pF}$ $V_{CC}=18\text{V}$

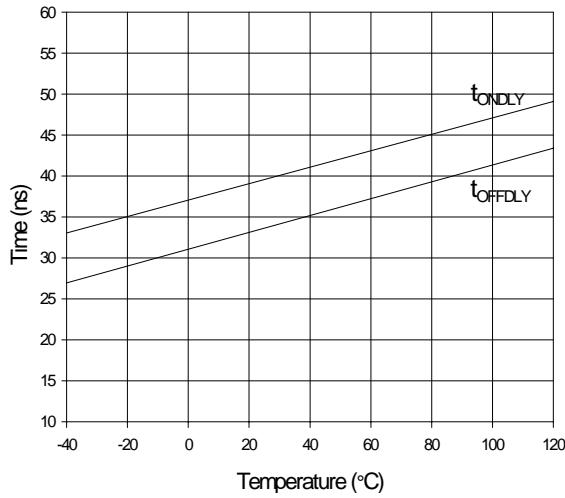


Fig. 18 Quiescent Supply Current vs. Junction Temperature
 $V_{CC}=18\text{V}$ $V_{IN}=5\text{V@1kHz}$

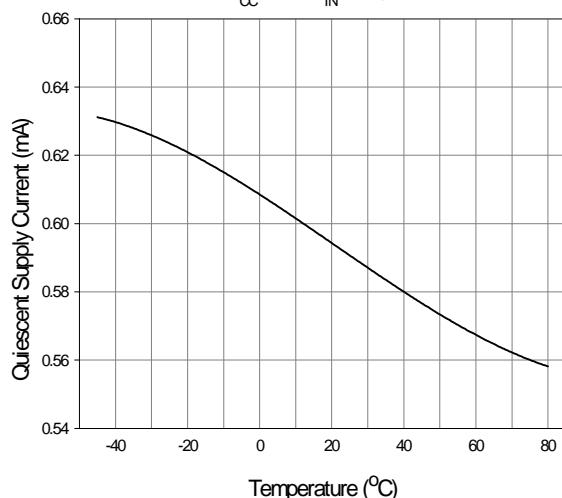


Fig. 19 P Channel Peak Output Current vs. Case Temperature
CI and YI Packages, $C_L=1\mu\text{F}$ $V_{CC}=18\text{V}$

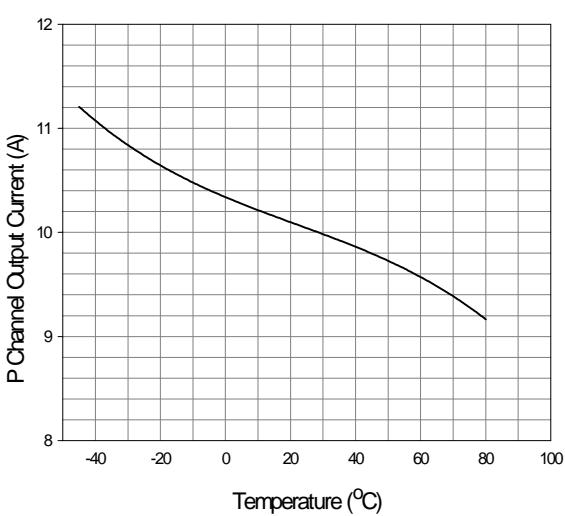


Fig. 20 N Channel Peak Output Current vs. Case Temperature
CI and YI Packages, $C_L=1\mu\text{F}$ $V_{CC}=18\text{V}$

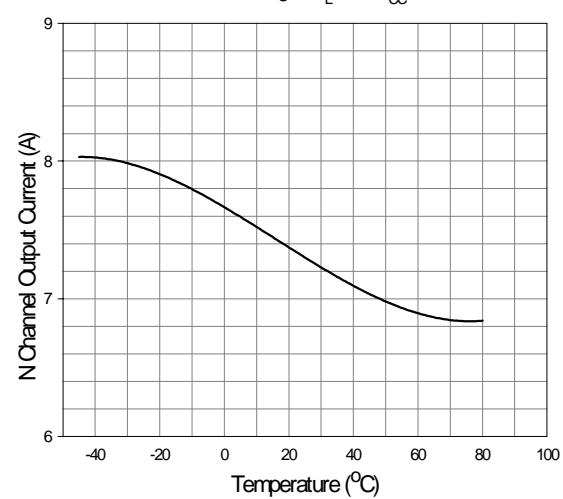
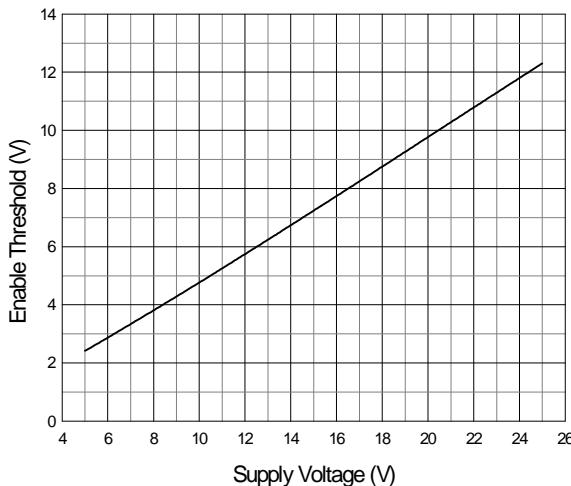
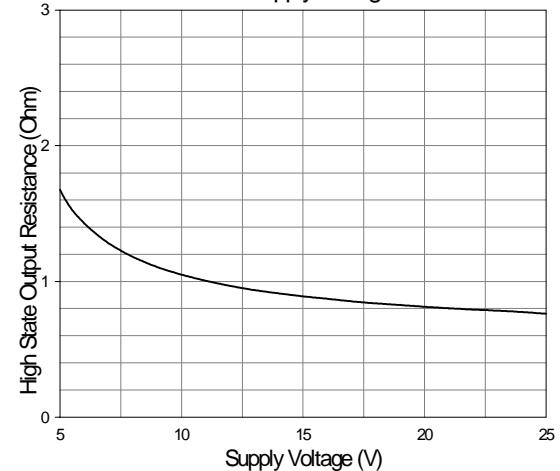
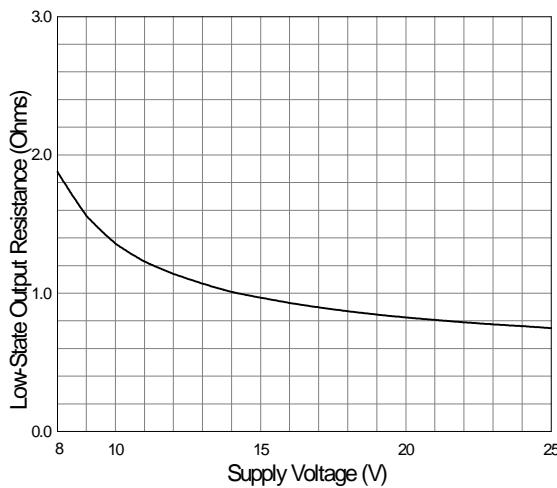
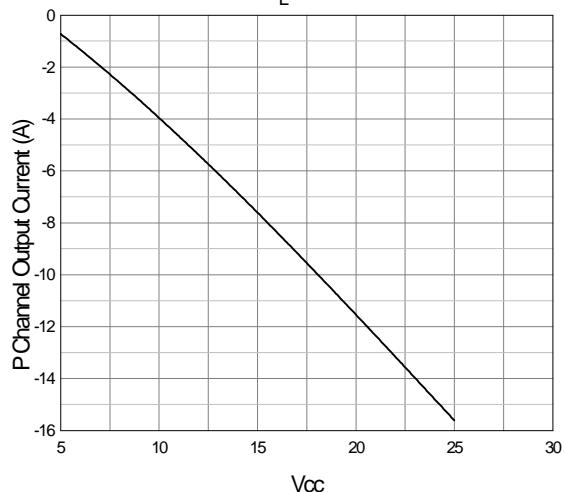
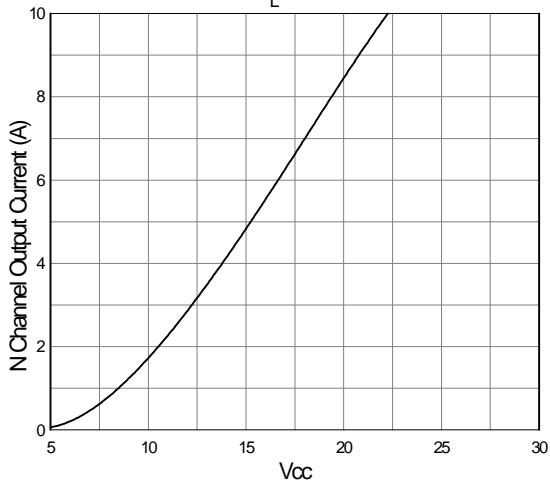
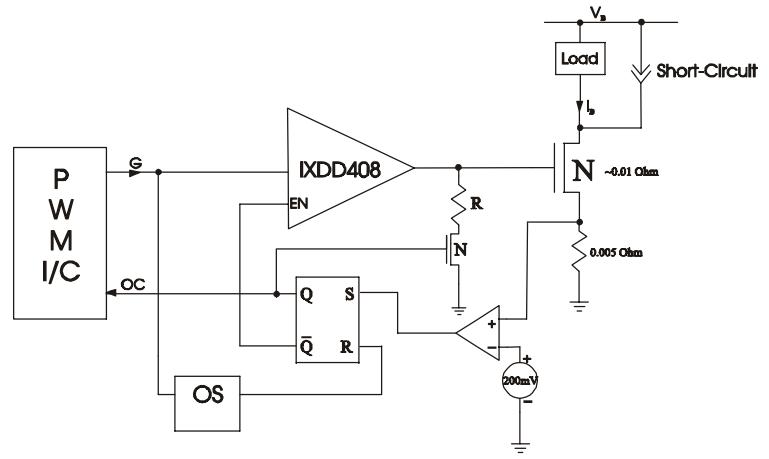


Fig. 21 Enable Threshold vs. Supply Voltage

Fig. 22 High State Output Resistance vs. Supply Voltage

Fig. 23 Low-State Output Resistance vs. Supply Voltage

Fig. 24 V_{cc} vs. P Channel Output Current C_L=15nF

Fig. 25 V_{cc} vs. N Channel Output Current C_L=15nF

Figure 26 - Typical Application Short Circuit di/dt Limit


APPLICATIONS INFORMATION

Short Circuit di/dt Limit

A short circuit in a high-power MOSFET module such as the VM0580-02F, (580A, 200V), as shown in Figure 26, can cause the current through the module to flow in excess of 1500A for 10 μ s or more prior to self-destruction due to thermal runaway. For this reason, some protection circuitry is needed to turn off the MOSFET module. However, if the module is switched off too fast, there is a danger of voltage transients occurring on the drain due to Ldi/dt, (where L represents total inductance in series with drain). If these voltage transients exceed the MOSFET's voltage rating, this can cause an avalanche breakdown.

The IXDD408 has the unique capability to softly switch off the high-power MOSFET module, significantly reducing these Ldi/dt transients.

Thus, the IXDD408 helps to prevent device destruction from *both* dangers; over-current, and avalanche breakdown due to di/dt induced over-voltage transients.

The IXDD408 is designed to not only provide ± 8 A under normal conditions, but also to allow its output to go into a high impedance state. This permits the IXDD408 output to control a separate weak pull-down circuit during detected overcurrent shutdown conditions to limit and separately control d_{VGS}/dt gate turnoff. This circuit is shown in Figure 27.

Referring to Figure 27, the protection circuitry should include a comparator, whose positive input is connected to the source of the VM0580-02. A low pass filter should be added to the input of the comparator to eliminate any glitches in voltage caused by the inductance of the wire connecting the source resistor to

ground. (Those glitches might cause false triggering of the comparator).

The comparator's output should be connected to a SRFF(Set Reset Flip Flop). The flip-flop controls both the Enable signal, and the low power MOSFET gate. Please note that CMOS 4000-series devices operate with a V_{CC} range from 3 to 15 VDC, (with 18 VDC being the maximum allowable limit).

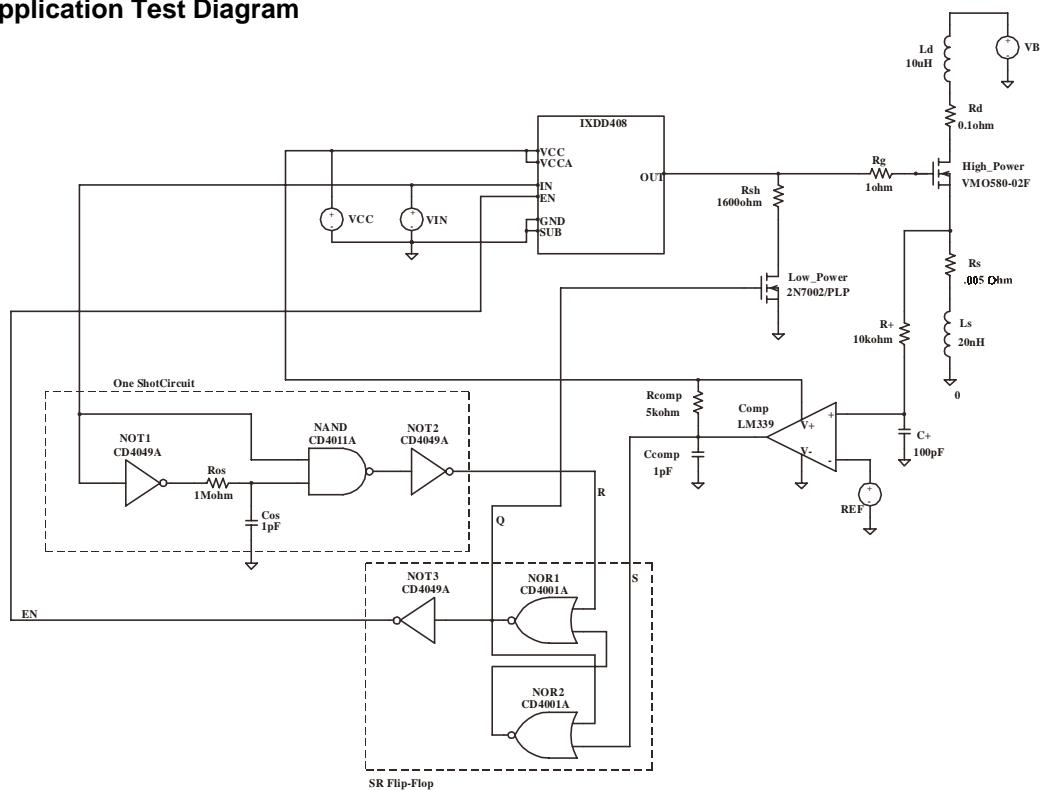
A low power MOSFET, such as the 2N7000, in series with a resistor, will enable the VMO580-02F gate voltage to drop gradually. The resistor should be chosen so that the RC time constant will be 100 μ s, where "C" is the Miller capacitance of the VMO580-02F.

For resuming normal operation, a Reset signal is needed at the SRFF's input to enable the IXDD408 again. This Reset can be generated by connecting a One Shot circuit between the IXDD408 Input signal and the SRFF restart input. The One Shot will create a pulse on the rise of the IXDD408 input, and this pulse will reset the SRFF outputs to normal operation.

When a short circuit occurs, the voltage drop across the low-value, current-sensing resistor, (R_s=0.005 Ohm), connected between the MOSFET Source and ground, increases. This triggers the comparator at a preset level. The SRFF drives a low input into the Enable pin disabling the IXDD408 output. The SRFF also turns on the low power MOSFET, (2N7000).

In this way, the high-power MOSFET module is softly turned off by the IXDD408, preventing its destruction.

Figure 27 - Application Test Diagram



Supply Bypassing and Grounding Practices, Output Lead inductance

When designing a circuit to drive a high speed MOSFET utilizing the IXDD408, it is very important to keep certain design criteria in mind, in order to optimize performance of the driver. Particular attention needs to be paid to **Supply Bypassing, Grounding**, and minimizing the **Output Lead Inductance**.

Say, for example, we are using the IXDD408 to charge a 5000pF capacitive load from 0 to 25 volts in 25ns...

Using the formula: $I = \Delta V C / \Delta t$, where $\Delta V = 25V$ $C = 5000pF$ & $\Delta t = 25ns$ we can determine that to charge 5000pF to 25 volts in 25ns will take a constant current of 5A. (In reality, the charging current won't be constant, and will peak somewhere around 8A).

SUPPLY BYPASSING

In order for our design to turn the load on properly, the IXDD408 must be able to draw this 5A of current from the power supply in the 25ns. This means that there must be very low impedance between the driver and the power supply. The most common method of achieving this low impedance is to bypass the power supply at the driver with a capacitance value that is a magnitude larger than the load capacitance. Usually, this would be achieved by placing two different types of bypassing capacitors, with complementary impedance curves, very close to the driver itself. (These capacitors should be carefully selected, low inductance, low resistance, high-pulse current-service capacitors). Lead lengths may radiate at high frequency due to inductance, so care should be taken to keep the lengths of the leads between these bypass capacitors and the IXDD408 to an absolute minimum.

GROUNDING

In order for the design to turn the load off properly, the IXDD408 must be able to drain this 5A of current into an adequate grounding system. There are three paths for returning current that need to be considered: Path #1 is between the IXDD408 and it's load. Path #2 is between the IXDD408 and it's power supply. Path #3 is between the IXDD408 and whatever logic is driving it. All three of these paths should be as low in resistance and inductance as possible, and thus as short as practical. In addition, every effort should be made to keep these three ground paths distinctly separate. Otherwise, (for instance), the returning ground current from the load may develop a voltage that would have a detrimental effect on the logic line driving the IXDD408.

OUTPUT LEAD INDUCTANCE

Of equal importance to Supply Bypassing and Grounding are issues related to the Output Lead Inductance. Every effort should be made to keep the leads between the driver and it's load as short and wide as possible. If the driver must be placed farther than 2" from the load, then the output leads should be treated as transmission lines. In this case, a twisted-pair should be considered, and the return line of each twisted pair should be placed as close as possible to the ground pin of the driver, and connect directly to the ground terminal of the load.

TTL to High Voltage CMOS Level Translation

The enable (EN) input to the IXDD408 is a high voltage CMOS logic level input where the EN input threshold is $\frac{1}{2} V_{CC}$, and may not be compatible with 5V CMOS or TTL input levels. The IXDD408 EN input was intentionally designed for enhanced noise immunity with the high voltage CMOS logic levels. In a typical gate driver application, $V_{CC} = 15V$ and the EN input threshold at 7.5V, a 5V CMOS logical high input applied to this typical IXDD408 application's EN input will be misinterpreted as a logical low, and may cause undesirable or unexpected results. The note below is for optional adaptation of TTL or 5V CMOS levels.

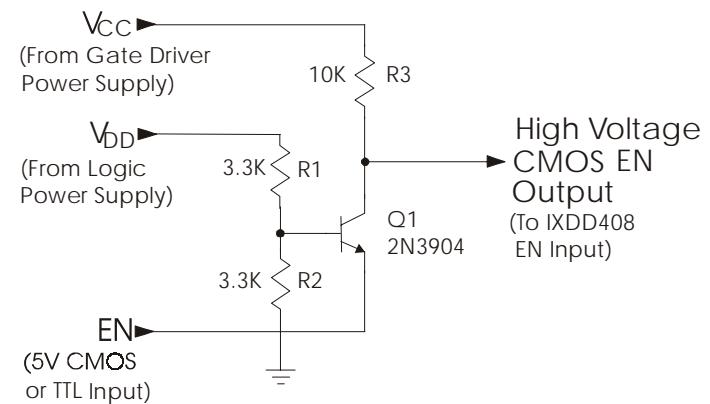
The circuit in Figure 28 alleviates this potential logic level misinterpretation by translating a TTL or 5V CMOS logic input to high voltage CMOS logic levels needed by the IXDD408 EN input. From the figure, V_{CC} is the gate driver power supply, typically set between 8V to 20V, and V_{DD} is the logic power supply, typically between 3.3V to 5.5V. Resistors R1 and R2 form a voltage divider network so that the Q1 base is positioned at the midpoint of the expected TTL logic transition levels.

A TTL or 5V CMOS logic low, $V_{TTLLOW} = \sim 0.8V$, input applied to the Q1 emitter will drive it on. This causes the level translator output, the Q1 collector output to settle to $V_{CESATQ1} + V_{TTLLOW} = \sim 2V$, which is sufficiently low to be correctly interpreted as a high voltage CMOS logic low ($< 1/3 V_{CC} = 5V$ for $V_{CC} = 15V$ given in the IXDD408 data sheet.)

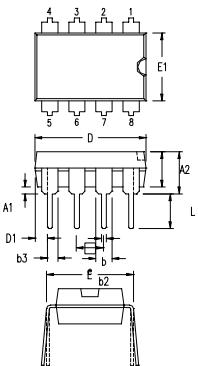
A TTL high, $V_{TTLHIGH} = \sim 2.4V$, or a 5V CMOS high, $V_{5VCMOSHIGH} = \sim 3.5V$, applied to the EN input of the circuit in Figure 28 will cause Q1 to be biased off. This results in Q1 collector being pulled up by R3 to $V_{CC} = 15V$, and provides a high voltage CMOS logic high output. The high voltage CMOS logical EN output applied to the IXDD408 EN input will enable it, allowing the gate driver to fully function as an 8 Amp output driver.

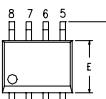
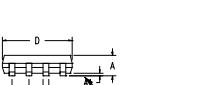
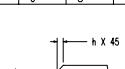
The total component cost of the circuit in Figure 28 is less than \$0.10 if purchased in quantities >1K pieces. It is recommended that the physical placement of the level translator circuit be placed close to the source of the TTL or CMOS logic circuits to maximize noise rejection.

Figure 28 - TTL to High Voltage CMOS Level Translator



Package Information

	<table border="1" style="border-collapse: collapse; width: 100%;"> <tr> <th style="width: 15%;">SYM</th> <th colspan="2">INCHES</th> <th colspan="2">MILLIMETERS</th> </tr> <tr> <th></th> <th>MIN</th> <th>MAX</th> <th>MIN</th> <th>MAX</th> </tr> </table> <table border="1" style="border-collapse: collapse; width: 100%;"> <tr> <td>A</td> <td>.140</td> <td>.180</td> <td>.356</td> <td>.457</td> </tr> <tr> <td>A1</td> <td>.015</td> <td>.040</td> <td>.038</td> <td>.102</td> </tr> <tr> <td>A2</td> <td>.125</td> <td>.145</td> <td>.318</td> <td>.368</td> </tr> <tr> <td>b</td> <td>.015</td> <td>.020</td> <td>.038</td> <td>.051</td> </tr> <tr> <td>b2</td> <td>.055</td> <td>.065</td> <td>.140</td> <td>.165</td> </tr> <tr> <td>b3</td> <td>.035</td> <td>.045</td> <td>.089</td> <td>.114</td> </tr> <tr> <td>c</td> <td>.009</td> <td>.012</td> <td>.023</td> <td>.030</td> </tr> <tr> <td>D</td> <td>.355</td> <td>.400</td> <td>.902</td> <td>.1016</td> </tr> <tr> <td>D1</td> <td>.010</td> <td>.040</td> <td>.025</td> <td>.102</td> </tr> <tr> <td>E</td> <td>.300</td> <td>.325</td> <td>.762</td> <td>.826</td> </tr> <tr> <td>E1</td> <td>.240</td> <td>.270</td> <td>.610</td> <td>.686</td> </tr> <tr> <td>e</td> <td>.100</td> <td>BSC</td> <td>2.54</td> <td>BSC</td> </tr> <tr> <td>eA</td> <td>.300</td> <td>BSC</td> <td>7.62</td> <td>BSC</td> </tr> <tr> <td>eB</td> <td>.300</td> <td>.430</td> <td>.762</td> <td>.1092</td> </tr> <tr> <td>L</td> <td>.120</td> <td>.140</td> <td>.305</td> <td>.356</td> </tr> </table>	SYM	INCHES		MILLIMETERS			MIN	MAX	MIN	MAX	A	.140	.180	.356	.457	A1	.015	.040	.038	.102	A2	.125	.145	.318	.368	b	.015	.020	.038	.051	b2	.055	.065	.140	.165	b3	.035	.045	.089	.114	c	.009	.012	.023	.030	D	.355	.400	.902	.1016	D1	.010	.040	.025	.102	E	.300	.325	.762	.826	E1	.240	.270	.610	.686	e	.100	BSC	2.54	BSC	eA	.300	BSC	7.62	BSC	eB	.300	.430	.762	.1092	L	.120	.140	.305	.356	<p>NOTE: THIS DRAWING MEETS ALL REQUIREMENT OF JEDEC OUTLINES MS-001 BA</p>	<p>DATE: 8/18/94 DWN: K. R. Choi</p> <p>TOLERANCE Specified $X+/-0.000, XXX+/-0.005$ $XXX+/-0.01 ANGLE+/-0.5$</p> <p>UNIT: INCH [MM] APR: SCALED 4 X APR:</p>	<p>TITLE: CASE OUTLINE OF 8 LEAD 0.3W P-DIP</p>	<p>DRAWING NO: CO 0035</p>
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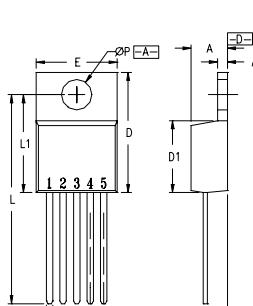
REV	DATE	ECN NO	DESCRIPTION	APR																																																																
																																																																				
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TOLERANCE
Unless Otherwise Specified
 $XX \pm .005$ INCHES
 $XX \pm .005$ MM
AMT: 1.5%

ITEM	1/16/01	DRAWING NO.	REV.
DATE:	1/16/01	DRW:	K. R. Choi
ITEMS:		REV.:	
INCHES	APR	0	
MM			

NOTES:

1. All metal surface are solder plated except
brimmed area.
2. Short lead of No. 3 is optional of IXYS.
3. No. 3 lead is connected to No. 6 lead (bottom
heat sink) internally.

REV	DATE	ECN NO	DESCRIPTION	
			APR	
				
SYM	INCHES	MILLIMETERS		
A A1 A2 b c D D1 E k L L1 P	MIN .170 .045 .090 .025 .580 .340 .390 0 .995 .470 .139	MAX .190 .055 .115 .040 .325 .370 .415 .014 .105 .510 .156	MIN 4.32 1.14 2.29 0.64 14.73 9.64 9.91 0 25.27 12.95 3.53	MAX 4.83 1.40 2.92 1.02 15.75 9.40 10.54 1.70 BSC 0.36 25.54 3.96
NOTE: This drawing will meet all dimensions requirement of JEDEC outlines TS-001AA and 5 lead version TO-220AB.				

NOTE: Mounting or solder tabs on all packages are connected to ground

Ordering Information

Part Number	Package Type	Temp. Range
IXDD408PI	8-Pin PDIP	-40°C to +85°C
IXDD408SI	8-Pin SOIC	-40°C to +85°C
IXDD408YI	5-Pin TO-263	-40°C to +85°C
IXDD408CI	5-Pin TO-220	-40°C to +85°C

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e-mail: sales@ixys.net

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e-mail: marcom@ixys.de

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An IXYS Company
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e-mail: deiinfo@directedenergy.com